

500mW Zener Diode Series

ZD5229ASH thru ZD5267ASH

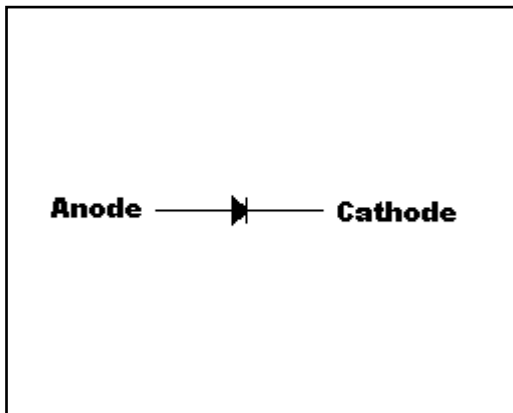
Description

The ZD5229ASH thru ZD5267ASH series covers zener voltage range from 4.3V to 75V, and is encapsulated in SOD-123 package, very suitable for low cost, low power voltage regulation application.

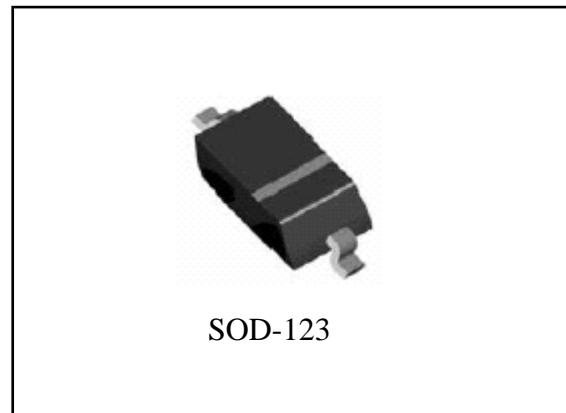
Features

- V_Z tolerance : $\pm 2\%$
- Ultra small surface mount package
- General purpose, medium current
- Planar die construction
- Pb-free lead plating and halogen-free package

Symbol

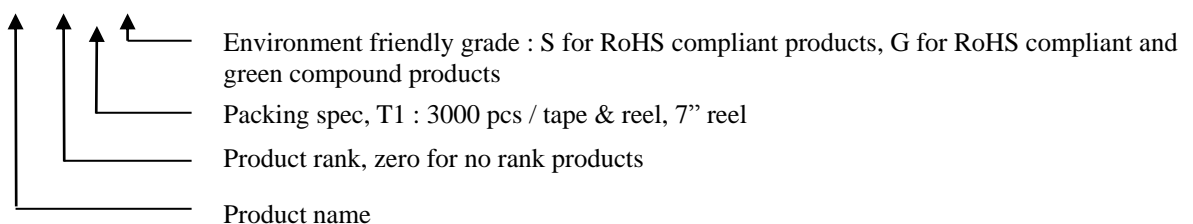


Outline



Ordering Information

Device	Package	Shipping
ZD52XXASH-0-T1-G	SOD-123 (Pb-free lead plating and halogen-free package)	3000 pcs / tape & reel





Absolute Maximum Ratings(Tj=25°C, unless otherwise specified)

- Maximum Temperatures
 Operating and Storage Temperature Range Tj,Tstg -65~+150 °C
- Maximum Forward Voltage @ If=10mA0.9V
- Maximum Power Dissipation
 Total Power Dissipation @TA=25 °C Ptot (Note 1)500 mW
- Thermal Resistance, Junction to Ambient RθJA250°C/W
 Thermal Resistance, Junction to Case RθJC150°C/W
- Maximum Z-current..... Ptot/Vz mA

Note : 1. Parts mounted on FR-5 board with area of 1inch × 1inch.

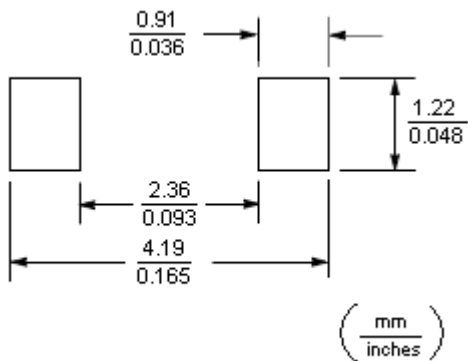
Electrical Characteristic (Ta=25°C, unless otherwise noted)

Device	Type Code	Nom. Zener Voltage			Max. Zener Impedance				Max. Zener Current	Max. Reverse Leakage Current	
		Vz@IZT (V)			ZZT	IZT	ZZK	IZK	IZM@Ta	IR	VR
		Nom.	Min.	Max.	(Ω)	(mA)	(Ω)	(mA)	(mA)	(μA)	(V)
ZD5229A	G4	4.3	4.21	4.39	22	20	2000	0.25	106	5.0	1.0
ZD5230A	G5	4.7	4.61	4.79	19	20	1900	0.25	97	5.0	2.0
ZD5231A	E1	5.1	5.00	5.20	17	20	1600	0.25	89	5.0	2.0
ZD5232A	E2	5.6	5.49	5.71	11	20	1600	0.25	81	5.0	3.0
ZD5233A	E3	6.0	5.88	6.12	7.0	20	1600	0.25	76	5.0	3.5
ZD5234A	E4	6.2	6.08	6.32	7.0	20	1000	0.25	73	5.0	4.0
ZD5235A	E5	6.8	6.66	6.94	5.0	20	750	0.25	67	3.0	5.0
ZD5236A	F1	7.5	7.35	7.65	6.0	20	500	0.25	61	3.0	6.0
ZD5237A	F2	8.2	8.04	8.36	8.0	20	500	0.25	55	3.0	6.5
ZD5238A	F3	8.7	8.53	8.87	8.0	20	600	0.25	55	3.0	6.5
ZD5239A	F4	9.1	8.92	9.28	10	20	600	0.25	50	3.0	7.0
ZD5240A	F5	10	9.80	10.20	17	20	600	0.25	45	3.0	8.0
ZD5241A	H1	11	10.78	11.22	22	20	600	0.25	41	2.0	8.4
ZD5242A	H2	12	11.76	12.24	30	20	600	0.25	38	1.0	9.1
ZD5243A	H3	13	12.74	13.26	13	9.5	600	0.25	35	0.5	9.9
ZD5244A	H4	14	13.72	14.28	15	9	600	0.25	32	0.1	10
ZD5245A	H5	15	14.70	15.30	16	8.5	600	0.25	30	0.1	11
ZD5246A	J1	16	15.68	16.32	17	7.8	600	0.25	28	0.1	12
ZD5248A	J3	18	17.64	18.36	21	7.0	600	0.25	25	0.1	14
ZD5250A	J5	20	19.60	20.40	25	6.2	600	0.25	23	0.1	15
ZD5251A	K1	22	21.56	22.44	29	5.6	600	0.25	21	0.1	17
ZD5252A	K2	24	23.52	24.48	33	5.2	600	0.25	19.1	0.1	18
ZD5254A	K4	27	26.46	27.54	41	5.0	600	0.25	16.8	0.1	21
ZD5255A	K5	28	27.44	28.56	44	4.5	600	0.25	16.2	0.1	21
ZD5256A	M1	30	29.40	30.60	49	4.2	600	0.25	15.1	0.1	23
ZD5257A	M2	33	32.34	33.66	58	3.8	700	0.25	13.8	0.1	25
ZD5258A	M3	36	35.28	36.72	70	3.4	700	0.25	12.6	0.1	27



ZD5259A	M4	39	38.22	39.78	80	3.2	800	0.25	11.6	0.1	30
ZD5260A	M5	43	42.14	43.86	93	3	900	0.25	10.6	0.1	33
ZD5261A	N1	47	46.06	47.94	105	2.7	1000	0.25	9.6	0.1	36
ZD5262A	N2	51	49.98	52.02	125	2.5	1100	0.25	8.8	0.1	39
ZD5263A	N3	56	54.88	57.12	150	2.2	1300	0.25	8.0	0.1	43
ZD5264A	N4	60	58.8	61.2	170	2.1	1400	0.25	7.5	0.1	46
ZD5265A	N5	62	60.76	63.24	185	2.0	1400	0.25	7.3	0.1	47
ZD5266A	P1	68	66.64	69.36	230	1.8	1600	0.25	6.6	0.1	52
ZD5267A	P2	75	73.5	76.5	270	1.7	1700	0.25	6.0	0.1	56

Recommended Soldering Footprint



Typical Characteristics

Typical Temperature Coefficient



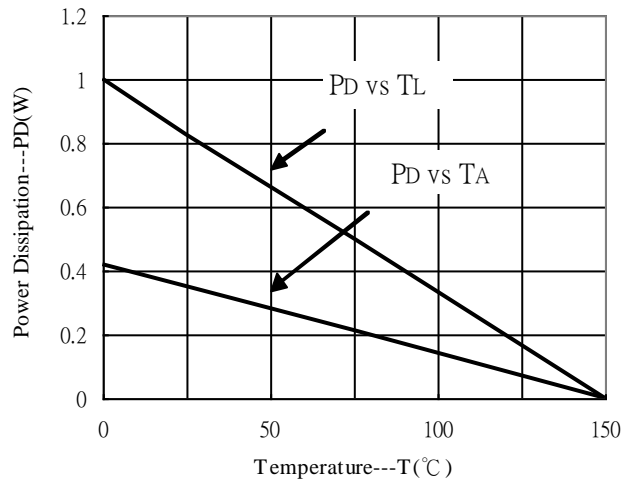
Dynamic Impedance



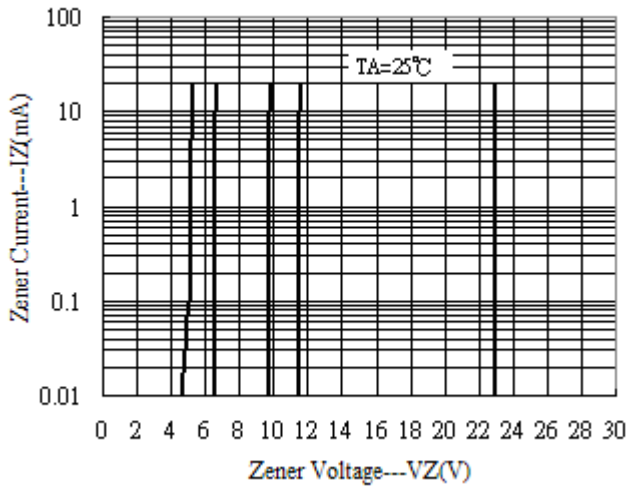
Typical Capacitance



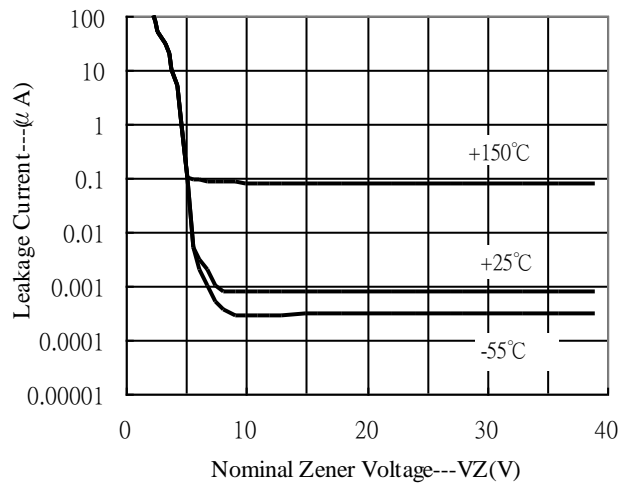
Power Derating Curve



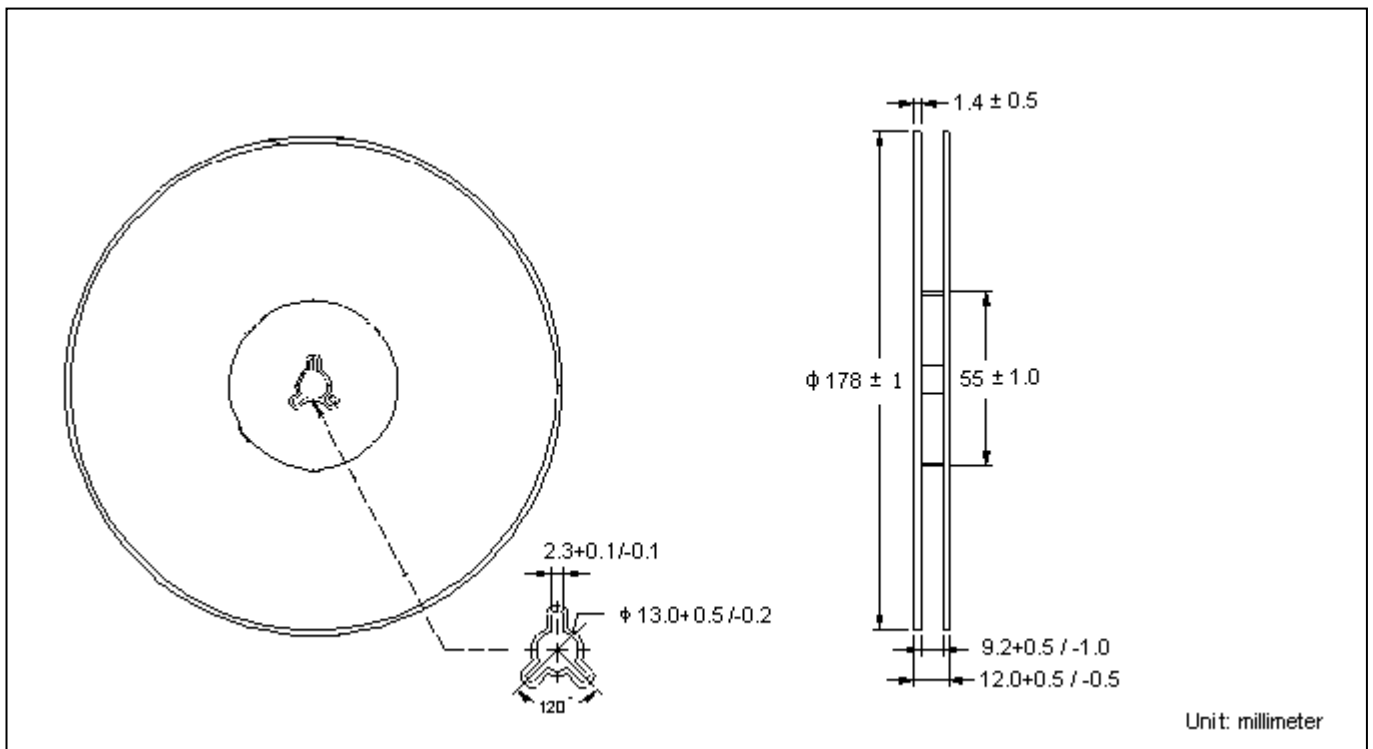
Zener Current vs Zener Voltage



Typical Leakage Current

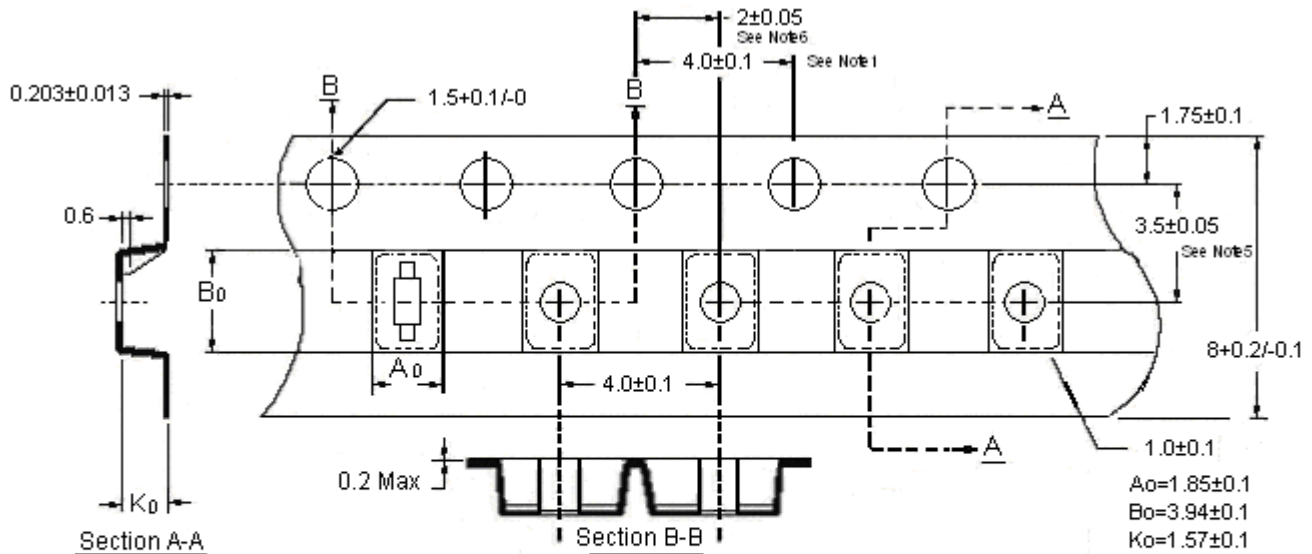


Reel Dimension



Carrier Tape Dimension





Notes:

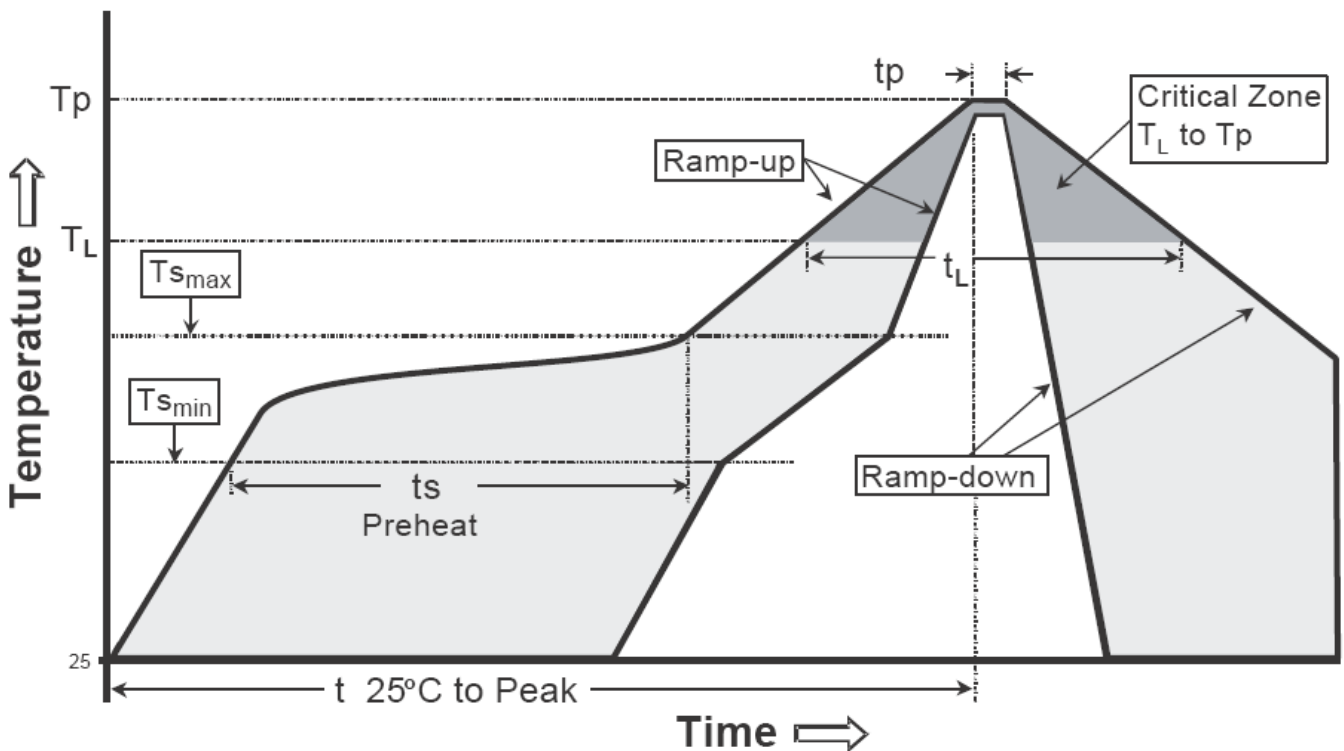
1. 10 sprocket hole pitch cumulative tolerance ± 0.2 .
2. Camber not to exceed 1mm in 100mm.
3. Material : conductive Black Polystyrene.
4. A_0 & B_0 measured on a plane 0.3mm above the bottom of the pocket.
5. K_0 measured from a plane on the inside bottom of the pocket to the top surface of the carrier.
6. Pocket position relative to sprocket hole measured as true position of pocket, not pocket hole.

Unit : millimeter

Recommended wave soldering condition

Product	Peak Temperature	Soldering Time
Pb-free devices	260 ± 5 °C	5 ± 1 / -1 seconds

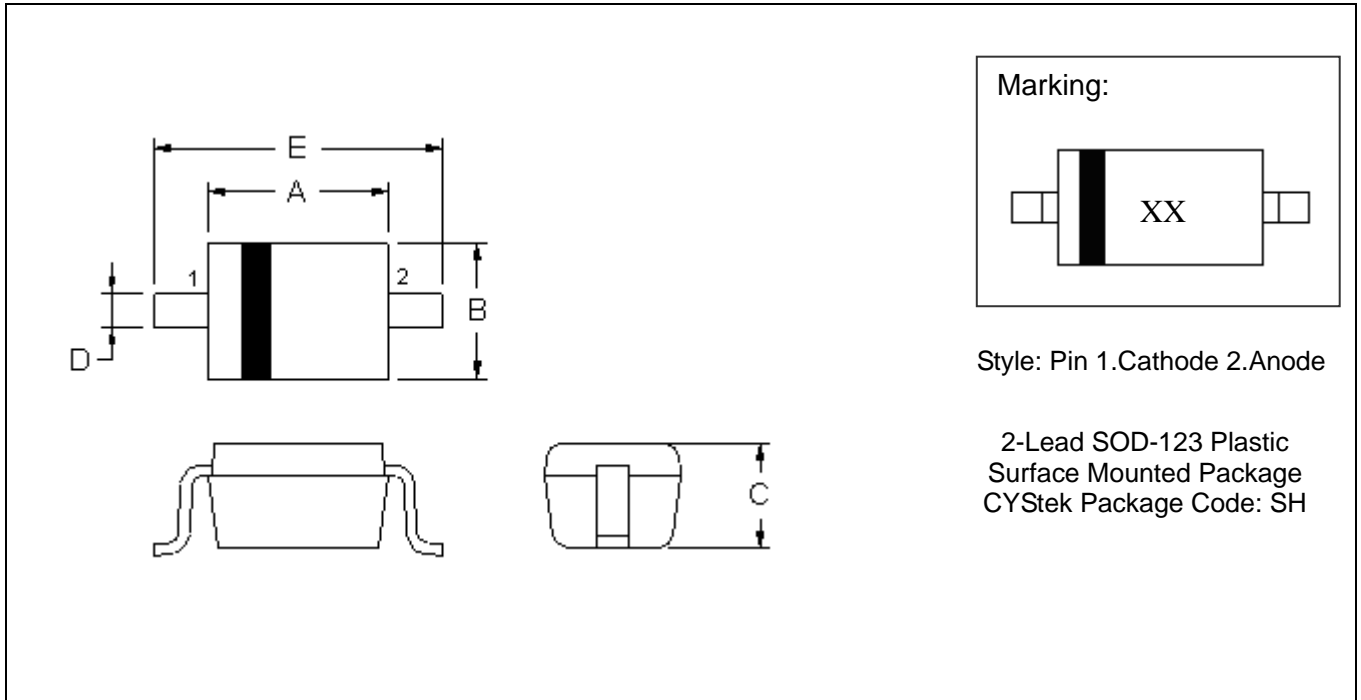
Recommended temperature profile for IR reflow



Profile feature	Sn-Pb eutectic Assembly	Pb-free Assembly
Average ramp-up rate (Tsmax to Tp)	3°C/second max.	3°C/second max.
Preheat		
-Temperature Min(Ts min)	100°C	150°C
-Temperature Max(Ts max)	150°C	200°C
-Time(ts min to ts max)	60-120 seconds	60-180 seconds
Time maintained above:		
-Temperature (TL)	183°C	217°C
- Time (tL)	60-150 seconds	60-150 seconds
Peak Temperature(Tp)	240 +0/-5 °C	260 +0/-5 °C
Time within 5°C of actual peak temperature(tp)	10-30 seconds	20-40 seconds
Ramp down rate	6°C/second max.	6°C/second max.
Time 25 °C to peak temperature	6 minutes max.	8 minutes max.

Note : All temperatures refer to topside of the package, measured on the package body surface.

SOD-123 Dimension



Style: Pin 1.Cathode 2.Anode

2-Lead SOD-123 Plastic
 Surface Mounted Package
 CYStek Package Code: SH

*: Typical

DIM	Inches		Millimeters		DIM	Inches		Millimeters	
	Min.	Max.	Min.	Max.		Min.	Max.	Min.	Max.
A	0.102	0.110	2.600	2.800	E	0.140	0.152	3.550	3.850
B	0.059	0.067	1.500	1.700					
C	0.041	0.049	1.050	1.250					
D	0.018	0.026	0.450	0.650					

Notes: 1.Controlling dimension : millimeters.
 2.Lead thickness specified per L/F drawing with solder plating.
 3.If there is any question with packing specification or packing method, please contact your local CYStek sales office.

Material:

- Lead: Pure tin plated
- Mold Compound: Epoxy resin family, flammability solid burning class: UL94V-0

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